

C-Band Radar - GaNInternally Pre-matched Discrete



IGN5259M20 IGN5259M20S

CERTIFIED C

Integra introduces the IGN5259M20 – an internally pre-matched discrete device based on gold metalized GaN technology.

• Output Power: ≥ 20W

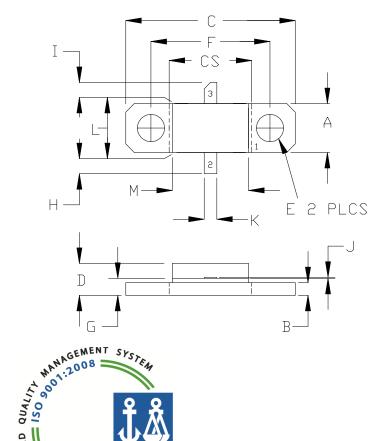
· Gain: 12dB typ

• Efficiency: ≥60% typ

• Also available in flangeless "S" package

• Frequency: 5.2-5.9GHz, PW = $300\mu s$, DF = 10%

• $V_{DD} = 36V$, $I_{DO} = 20mA$



'S' VERSION USE DIM CS NON 'S' VERSION USE DIM C

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.225	0.235	5.71	5.96
В	0.055	0.065	1.40	1.65
С	0.795	0.805	20.19	20.44
CS	0.385	0.395	9.78	10.03
D	0.140	0.160	3.55	4.06
E	0.125	0.135	3.18	3.43
F	0.557	0.567	14.14	14.40
G	0.077	0.087	1.95	2.20
Н	0.093	0.107	2.36	2.72
I	0.093	0.107	2.36	2.72
J	0.004	0.006	0.10	0.15
K	0.055	0.065	1.40	1.65
L	0.225	0.235	5.71	5.96
М	0.355	0.365	9.01	9.27

PIN	SCHEDULE
1	SOURCE
2	GATE
3	DRAIN

IGN5259M20-IGN5259M20S-PR1-NPS-NC Available Now

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